

Supporting Information

Design Two-Dimensional Electron Gas via Polarization Discontinuity from Large-Scale First-Principles Calculations

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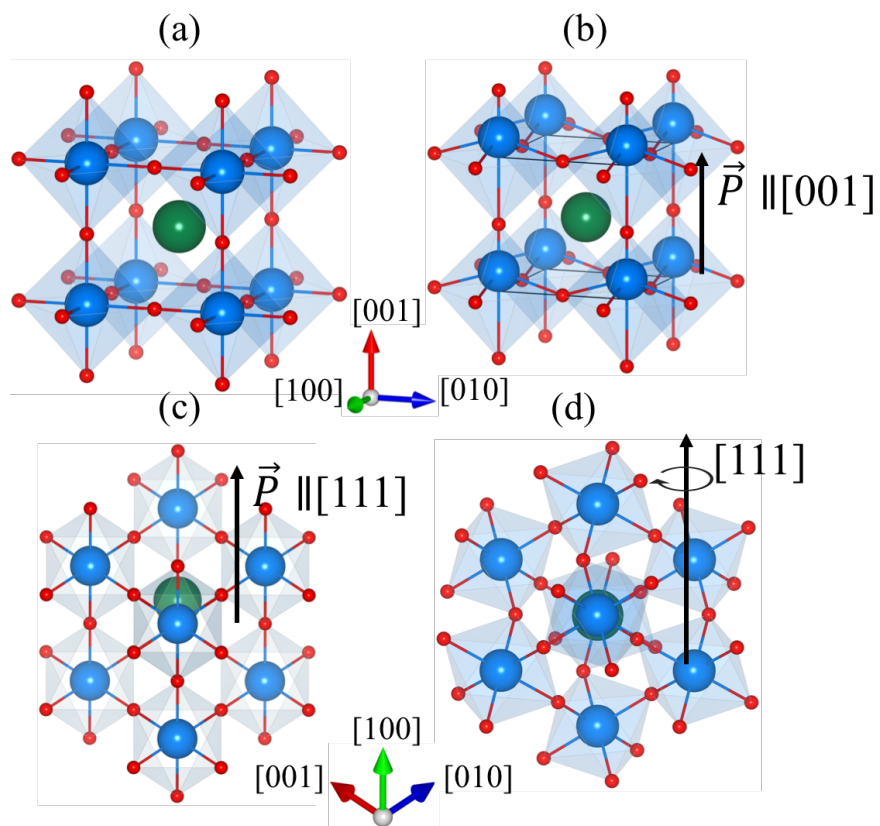


Figure S1. Scheme of perovskite oxide ABO_3 structures: (a) cubic, (b) tetragonal, (c) rhombohedral, and (d) structure with oxygen octahedral rotates along the $[111]$ direction.

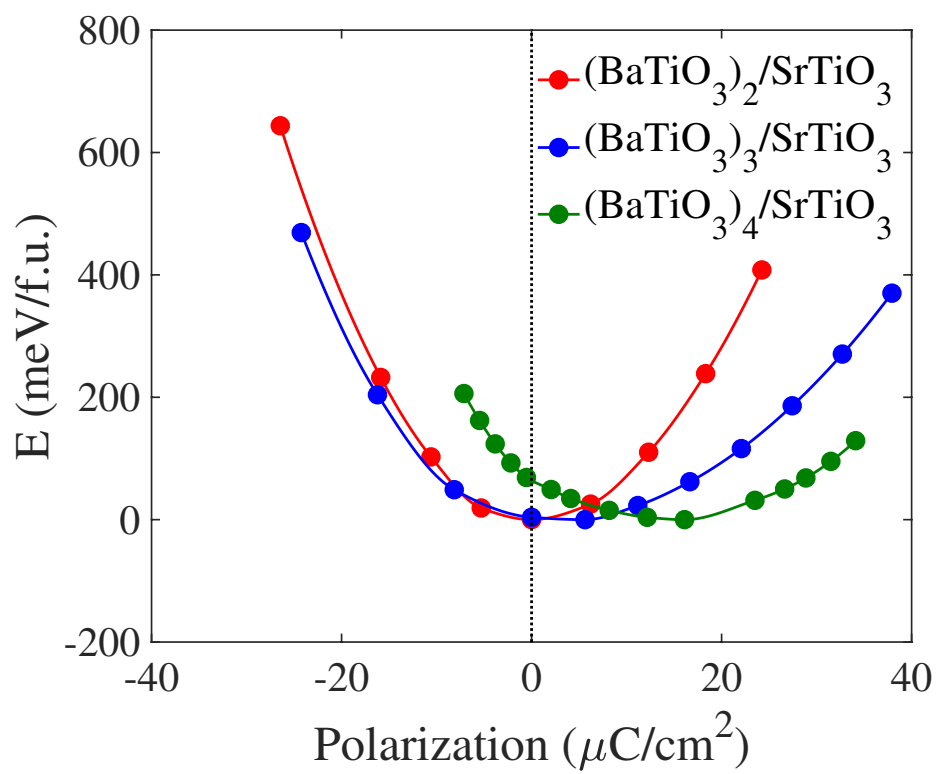


Figure S2. Calculated total energy per unit cell of the film as a function of the average polarization for BaTiO₃/SrTiO₃ heterostructure (HS) models with different film thickness. The reference energy (zero) is taken from the lowest energy of each system.

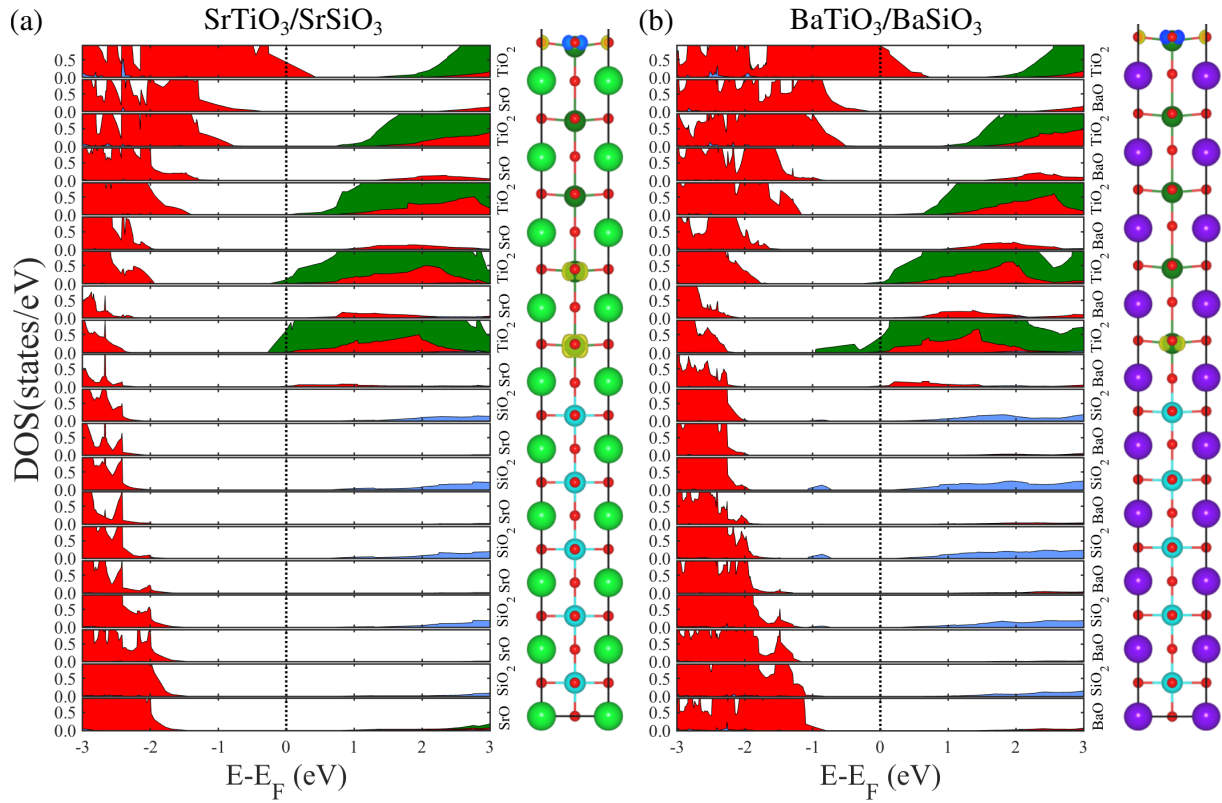


Figure S3. Calculated layer-resolved partial DOS for (a) SrTiO₃/SrSiO₃ and (b) BaTiO₃/BaSiO₃, along with their charge density plots projected on the bands forming the metallic states. The vertical dash line at zero-point energy shows the Fermi level. The solid blue, red, and green color indicates *s*, *p*, and *d* orbital, respectively.

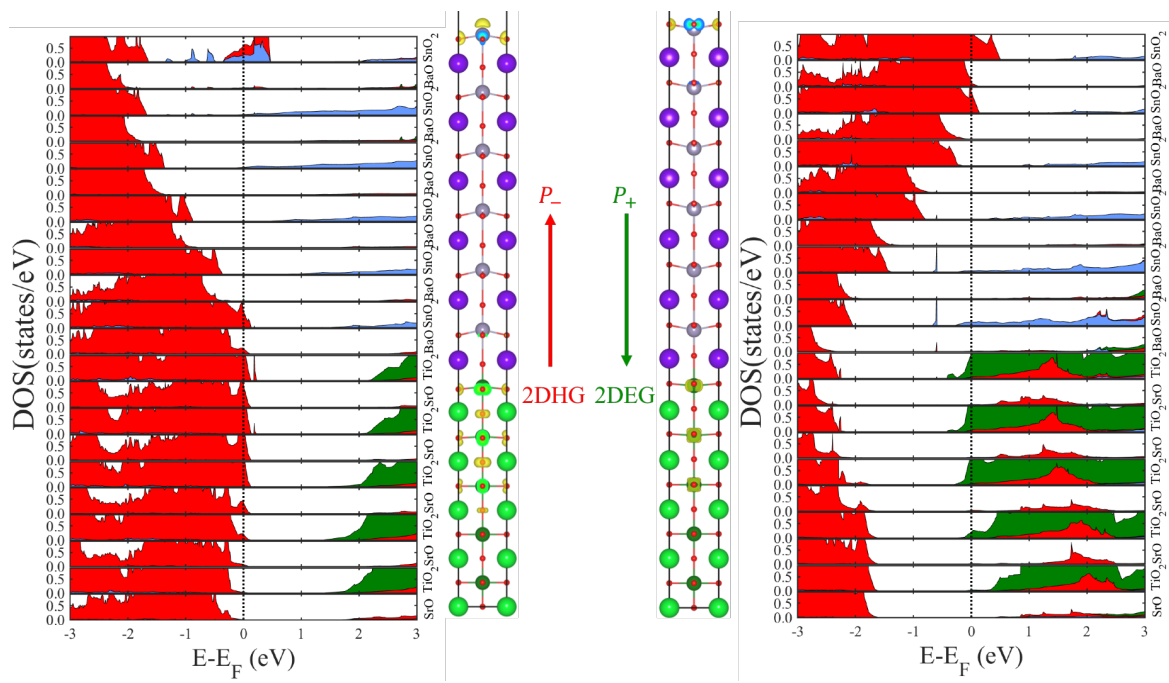


Figure S4. Calculated layer-resolved partial DOS for P_+ and P_- states in $\text{BaSnO}_3/\text{SrTiO}_3$ HS, along with their charge density plots projected on the bands forming the metallic states.

Table S1. Calculated electron effective mass m^* (in unit of free electron mass) along the M- Γ and Γ -X path for BaTiO₃/SrTiO₃, CaZrO₃/YbZrO₃, CaZrO₃/CaHfO₃, CaSnO₃/BaSiO₃, BaSiO₃/CaGeO₃, and CaZrO₃/SrSnO₃ HS models.

Systems	m^*/m_e		
	M- Γ	Γ -X	Average
BaTiO ₃ /SrTiO ₃	0.56	0.46	0.51
CaZrO ₃ /YbZrO ₃	0.40	0.38	0.39
CaZrO ₃ /CaHfO ₃	0.51	0.40	0.46
CaSnO ₃ /BaSiO ₃	0.34	0.31	0.33
BaSiO ₃ /CaGeO ₃	0.30	0.24	0.27
CaZrO ₃ /SrSnO ₃	0.34	0.28	0.31